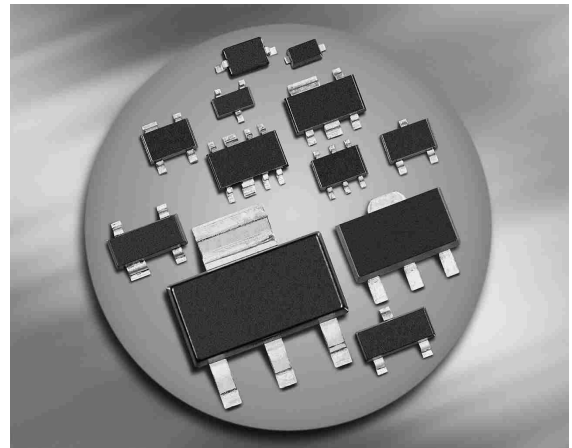
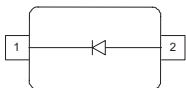


Silicon Variable Capacitance Diode

- Designed for tuning wideband CATV-Tuners
- High capacitance ratio C_{1V}/C_{28V} (typ. 18.3)
- Low series resistance
- Excellent uniformity and matching due to "in-line" matching assembly procedure



BB679-02V



Type	Package	Configuration	L_S (nH)	Marking
BB679-02V*	SC79	single	0.6	K

* Preliminary

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	30	V
Peak reverse voltage ($R \geq 5\text{k}\Omega$)	V_{RM}	35	
Forward current	I_F	20	mA
Operating temperature range	T_{op}	-55 ... 125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 ... 150	

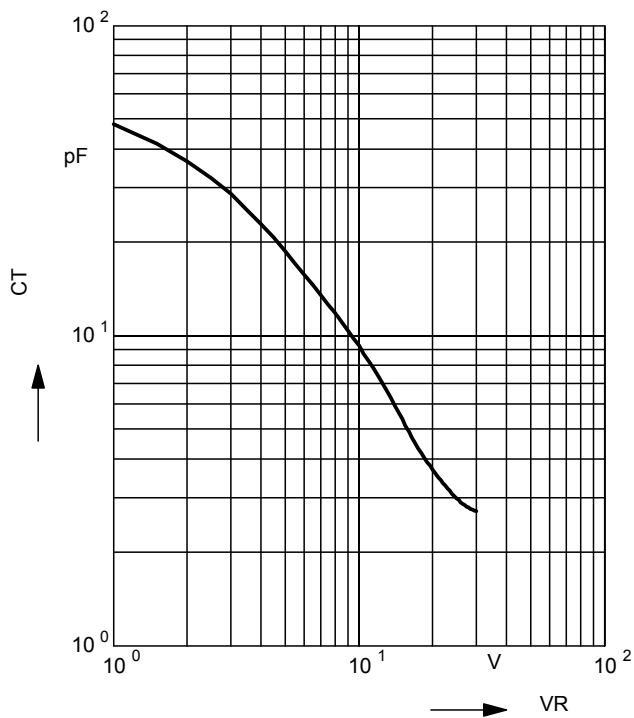
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Reverse current	I_R				nA
$V_R = 30\text{ V}$		-	-	10	
$V_R = 30\text{ V}, T_A = 85\text{ }^{\circ}\text{C}$		-	-	100	
AC Characteristics					
Diode capacitance	C_T				pF
$V_R = 1\text{ V}, f = 1\text{ MHz}$		43.5	47.5	51.5	
$V_R = 2\text{ V}, f = 1\text{ MHz}$		33	36	38.8	
$V_R = 25\text{ V}, f = 1\text{ MHz}$		2.55	2.75	2.95	
$V_R = 28\text{ V}, f = 1\text{ MHz}$		2.4	2.6	2.8	
Capacitance ratio	C_{T1}/C_{T28}	16.5	18.3	20	-
$V_R = 1\text{ V}, V_R = 28\text{ V}, f = 1\text{ MHz}$					
Capacitance ratio	C_{T2}/C_{T25}	12	13.1	14.5	
$V_R = 2\text{ V}, V_R = 25\text{ V}, f = 1\text{ MHz}$					
Capacitance matching ¹⁾	$\Delta C_T/C_T$	-	-	2	%
$V_R = 1\text{ V}, V_R = 28\text{ V}, f = 1\text{ MHz}$					
Series resistance	r_S	-	0.6	0.8	Ω
$V_R = 5\text{ V}, f = 470\text{ MHz}$					

¹For details please refer to Application Note 047.

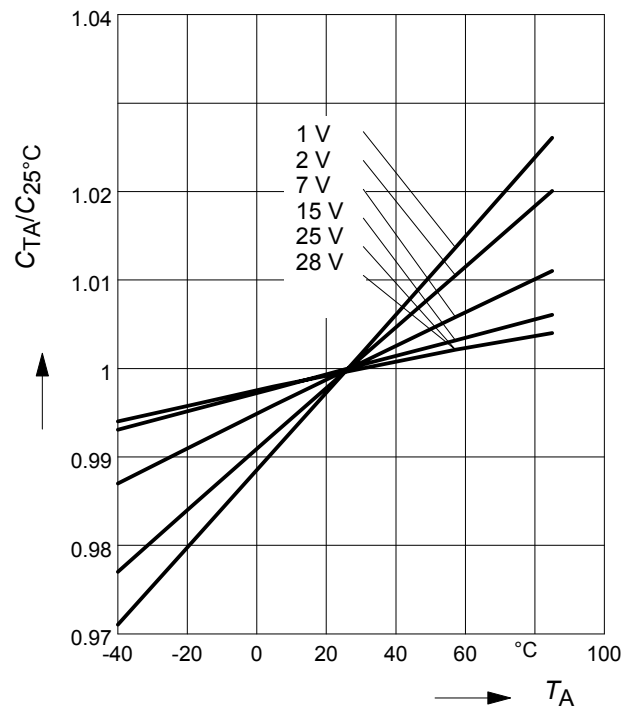
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$

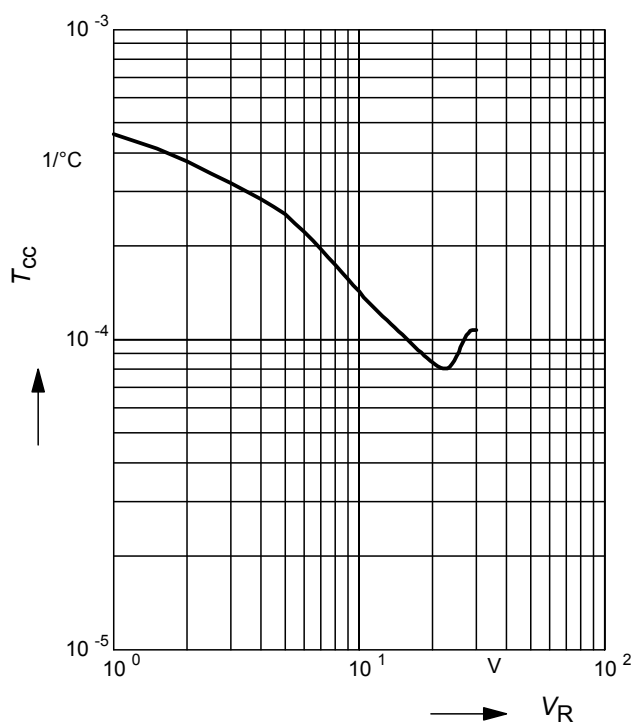


Normalized diode capacitance

$C_{(T_A)}/C_{(25^\circ\text{C})} = f(T_A); f = 1\text{MHz}$

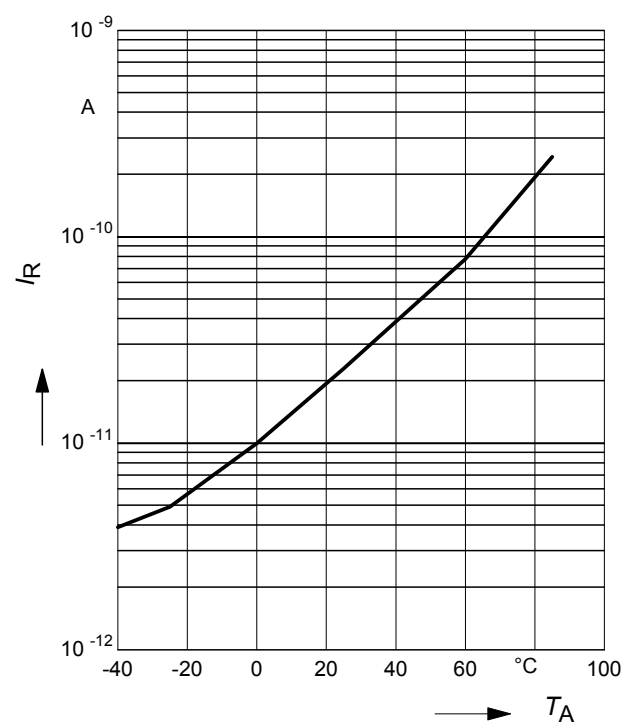


Temperature coefficient of the diode capacitance $T_{CC} = f(V_R)$



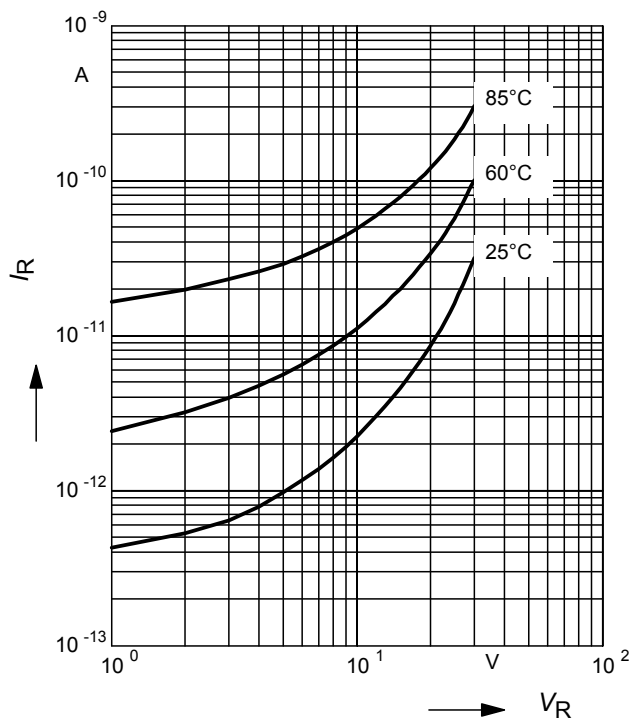
Reverse current $I_R = f(T_A)$

$V_R = 28\text{ V}$



Reverse current $I_R = f(V_R)$

$T_A = \text{Parameter}$



Reverse voltage $V_{BR} = f(T_A)$

$I_R = 5\mu\text{A}$

